

GENERAL PURPOSE JFET INPUT OPERATIONAL AMPLIFIERS

Features

- Low Power Consumption
- Wide Common-Mode and Differential Voltage Ranges
- Low Input Bias and Offset Currents
- Output Short-Circuit Protection
- Low Total Harmonic Distortion...0.003% Typ
- High Input Impedance...JFET-Input Stage
- Latch-Up-Free Operation
- High Slew Rate...13V/ μ s Typ
- Common-Mode Input Voltage Range Includes V_{CC+}
- SOP-8L: Available in "Green" Molding Compound (No Br, Sb)
- Lead Free Finish/ RoHS Compliant (Note 1)

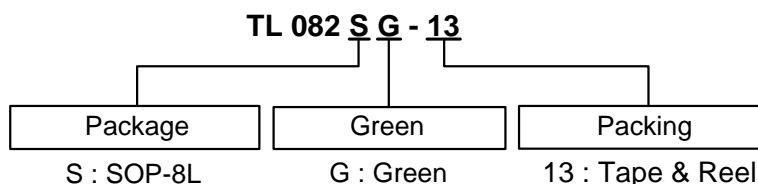
General Description

The JFET-input operational amplifier family is designed to offer a wider selection than any previously developed operational amplifier family. Each of these JFET-input operational amplifiers incorporates well-matched, high-voltage JFET and bipolar transistors in a monolithic integrated circuit. The devices feature high slew rates, low input bias and offset currents, and low offset-voltage temperature coefficient.

Applications

- Active filters
- Audio pre-amps
- Sample and holds
- Peak detectors

Ordering Information

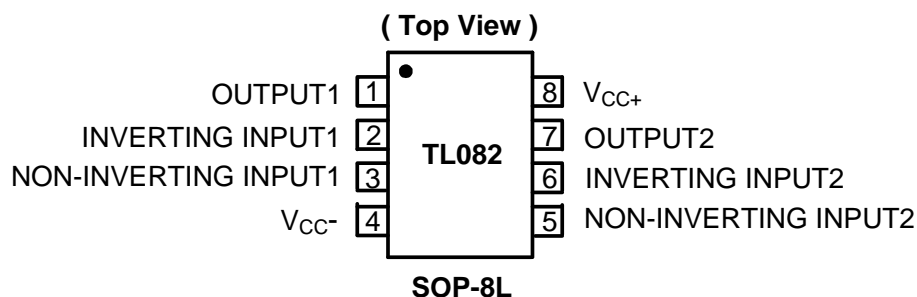


Device	Package Code	Packaging (Note 2)	13" Tape and Reel	
			Quantity	Part Number Suffix
TL082SG-13	S	SOP-8L	2500/Tape & Reel	-13

Notes: 1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied. Please visit our website at http://www.diodes.com/products/lead_free.html
 2. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.

Pin Assignments

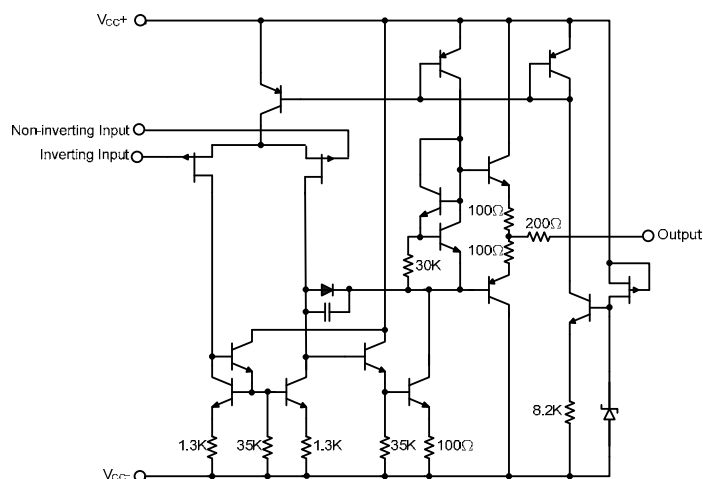
(1) Dual channel SOP-8L



Pin Descriptions

Pin Name	Pin No.	Description
OUTPUT1	1	Channel 1 Output
INVERTING INPUT1	2	Channel 1 Inverting Input
NON-INVERTING INPUT1	3	Channel 1 Non-inverting Input
V _{CC} -	4	Supply Voltage
NON-INVERTING INPUT2	5	Channel 2 Non-inverting Input
INVERTING INPUT2	6	Channel 2 Inverting Input
OUTPUT2	7	Channel 2 Output
V _{CC} +	8	Supply Voltage

Block Diagram



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Absolute Maximum Ratings (Note 8)

Symbol	Parameter	Rating	Unit
V_{CC+}	Supply Voltage + (Note 3)	+18	V
V_{CC-}	Supply Voltage - (Note 3)	-18	V
V_I	Input voltage (Notes 3 and 5)	± 15	V
V_{ID}	Differential input Voltage, V_{ID} (Note 4)	± 30	V
	Duration of output short circuit (Note 6)	Unlimited	
P_D	Power Dissipation (Note 7)	860	mW
T_J	Operating Junction Temperature Range	150	$^{\circ}\text{C}$
T_{ST}	Storage Temperature Range	-65 to +150	$^{\circ}\text{C}$

Notes: 3. ALL voltage values, except differential voltages, are with respect to the midpoint between V_{CC+} and V_{CC-} .
4. Differential voltage are at the non-inverting input terminal with respect to the inverting input terminal.
5. The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15V, whichever is less.
6. The output may be shorted to ground or either supply. Temperature and/or supply voltage must be limited to ensure that the dissipation rating is not exceeded.
7. Maximum power dissipation is a function of $T_J(\text{max})$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(\text{max}) - T_A) / \theta_{JA}$. Operating at the absolute maximum T_J of 150 $^{\circ}\text{C}$ can affect reliability

Recommended Operating Conditions (Note 8)

Symbol	Description	Rating	Unit
$V_{CC\pm}$	Supply Voltage	± 15	V
T_A	Operating Ambient Temperature Range	-40 to +85	$^{\circ}\text{C}$

Notes: 8. Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Recommended Operating Conditions indicate conditions for which the device is intended to be functional, but specific performance is not guaranteed. For guaranteed specifications and the test conditions, see the Electrical Characteristics.

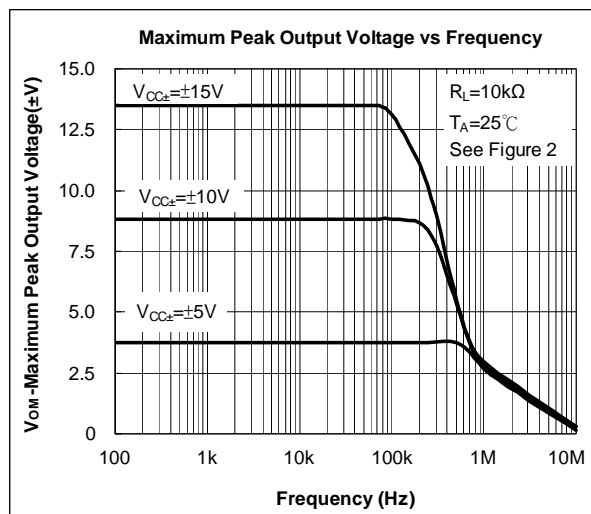
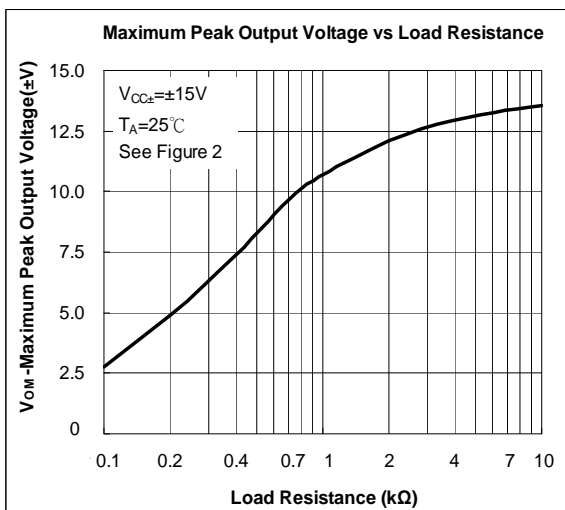
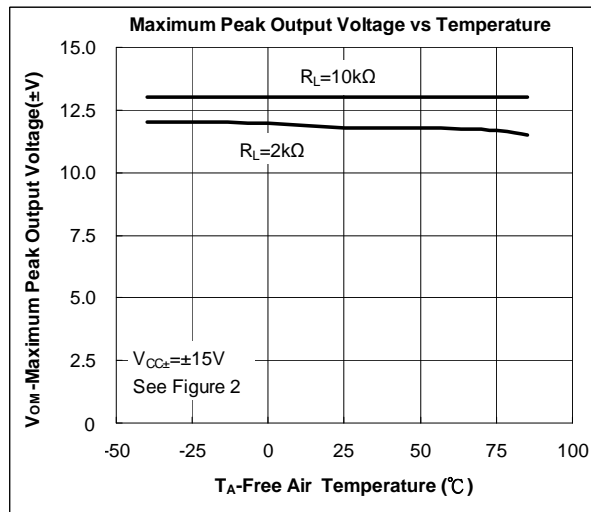
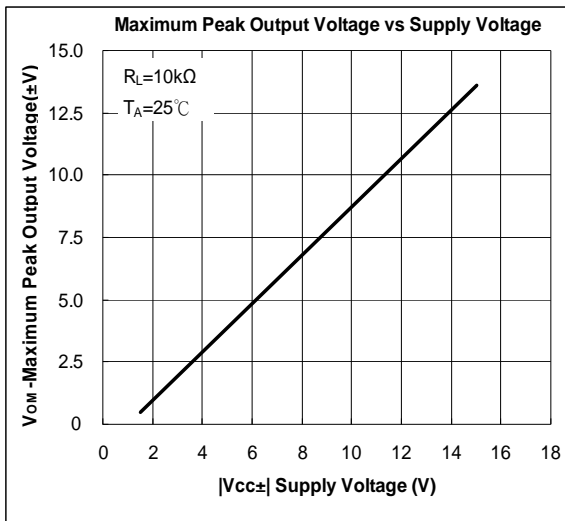
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Electrical Characteristics ($V_{CC\pm} = \pm 15V$, $T_A = 25^\circ C$; unless otherwise noted)

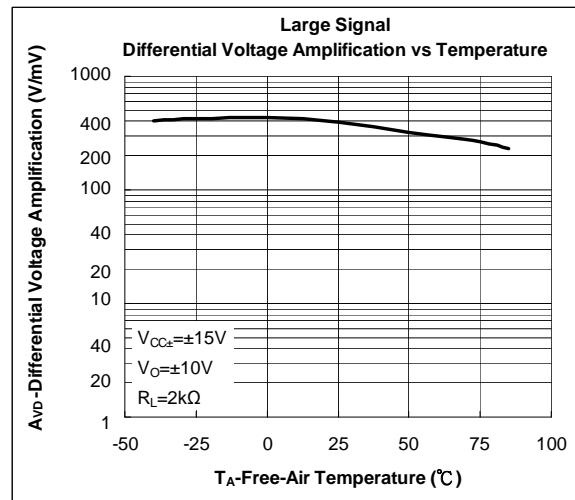
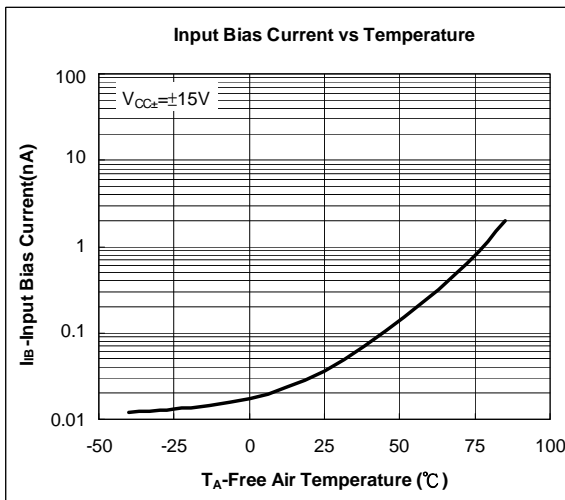
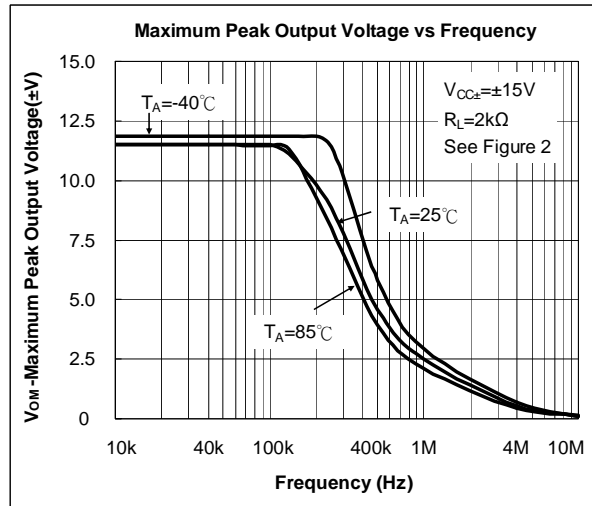
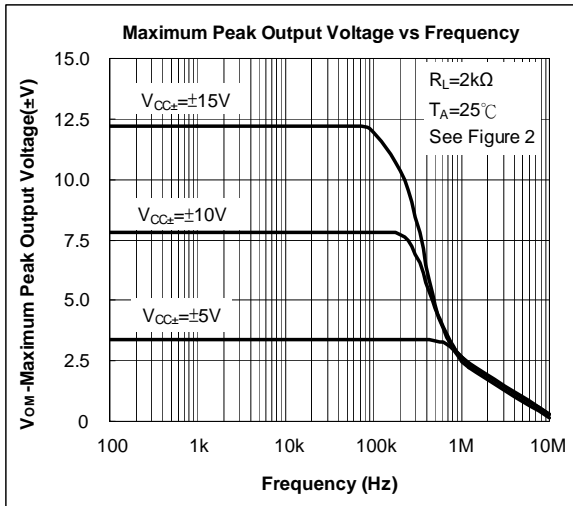
Symbol	Parameter	Test Conditions	Min	Typ.	Max	Unit
V_{IO}	Input Offset Voltage	$V_O=0$, $R_S=50\Omega$ $T_A=25^\circ C$ $T_A= \text{full range}$		3 9	6 9	mV
$^aV_{IO}$	Temperature Coefficient of Input Offset Voltage	$V_O=0$, $R_S=50\Omega$, $T_A= \text{full range}$		18		$\mu V/^\circ C$
I_{IO}	Input Offset Current	$V_O=0$ $T_A=25^\circ C$ $T_A= \text{full range}$		5 10	100 10	pA nA
I_{IB}	Input Bias Current	$V_O=0$ $T_A=25^\circ C$ $T_A= \text{full range}$		30 20	200 20	pA nA
V_{ICR}	Common Mode Input Voltage Range		± 11	-12~+15		V
V_{OM}	Maximum Peak Output Voltage Swing	$R_L=10k\Omega$, $T_A=25^\circ C$ $R_L \geq 10k\Omega$, $T_A= \text{full range}$ $R_L \geq 2k\Omega$	± 12 ± 12 ± 10	± 13.5 ± 12		V
A_{VD}	Large Signal Differential Voltage Amplification	$V_O=\pm 10V$, $R_L \geq 2k\Omega$ $T_A=25^\circ C$ $T_A= \text{full range}$	50 25	200		V/mV
B_1	Unity Gain Bandwidth			3		MHz
r_i	Input Resistance	$T_A=25^\circ C$		10^{12}		Ω
CMRR	Common Mode Rejection Ratio	$V_{IC}=V_{ICRmin}$, $V_O=0$ $R_S=50\Omega$, $T_A=25^\circ C$	75	86		dB
k_{SVR}	Supply Voltage Rejection Ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC}=\pm 9$ to $\pm 15V$ $V_O=0$ $R_S=50\Omega$, $T_A=25^\circ C$	80	86		dB
I_{CC}	Supply Current (each amplifier)	$V_O=0$, $T_A=25^\circ C$ No load		1.4	2.8	mA
V_{O1}/V_{O2}	Crosstalk Attenuation	$A_{VD}=100$, $T_A=25^\circ C$		120		dB
SR	Slew Rate at Unity Gain	$V_I=10V$, $C_L=100pF$, $R_L=2k\Omega$ (See Figure 1) $T_A=25^\circ C$ $T_A= \text{full range}$	8 5	13		V/ μs
t_r	Rise Time	$V_I=20mV$, $R_L=2k\Omega$, $C_L=100pF$ (See Figure 1)		0.05		μs
	Overshoot Factor			20		%
V_n	Equivalent Input Noise Voltage	$R_S=20\Omega$ $f=1kHz$ $f=10Hz$ to $10kHz$		18 4		nV/\sqrt{Hz} μV
I_n	Equivalent Input Noise Current	$R_S=20\Omega$, $f=1kHz$		0.01		pA/\sqrt{Hz}
THD	Total Harmonic Distortion	$V_{I rms}=6V$, $A_{VD}=1$, $R_L \geq 2k\Omega$, $R_S \leq 1k\Omega$, $f=1kHz$		0.003		%
θ_{JA}	Thermal Resistance Junction-to-Ambient	SOP-8L (Note 9)		145		$^\circ C/W$
θ_{JC}	Thermal Resistance Junction-to-Case	SOP-8L (Note 9)		35		$^\circ C/W$

Notes: 9. Test condition for SOP-8L: Devices mounted on FR-4 substrate PC board, with minimum recommended pad layout.

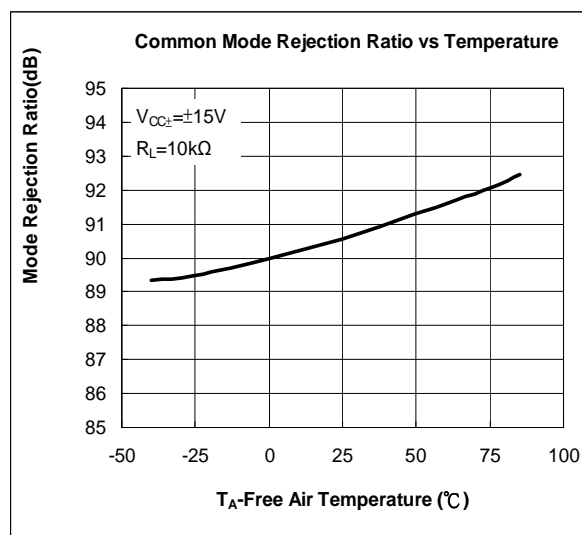
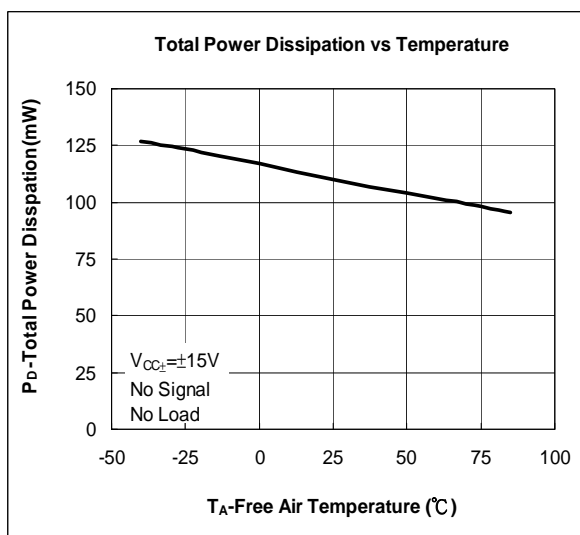
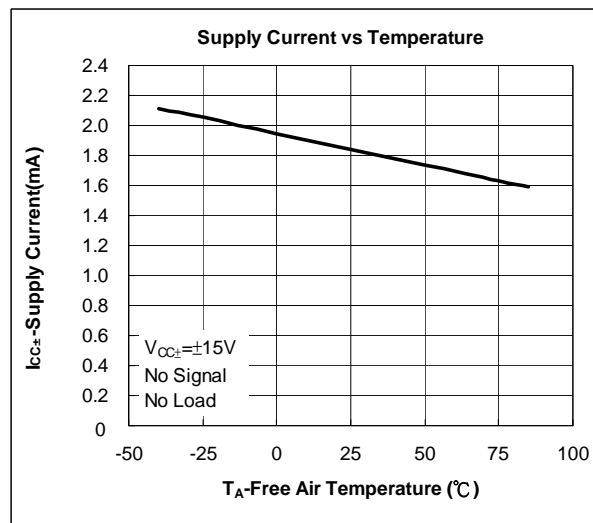
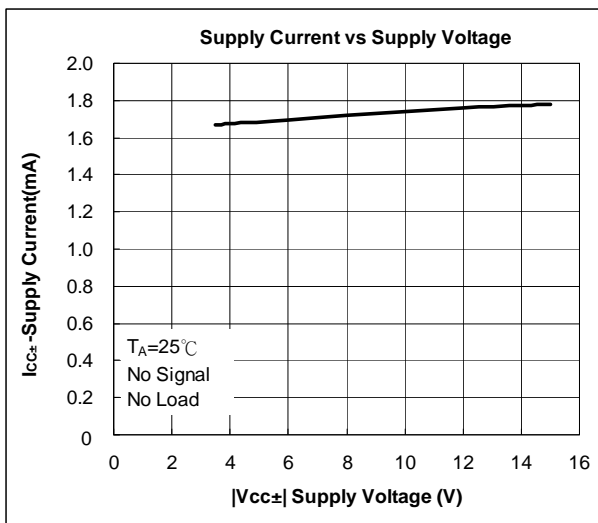
Typical Performance Characteristics



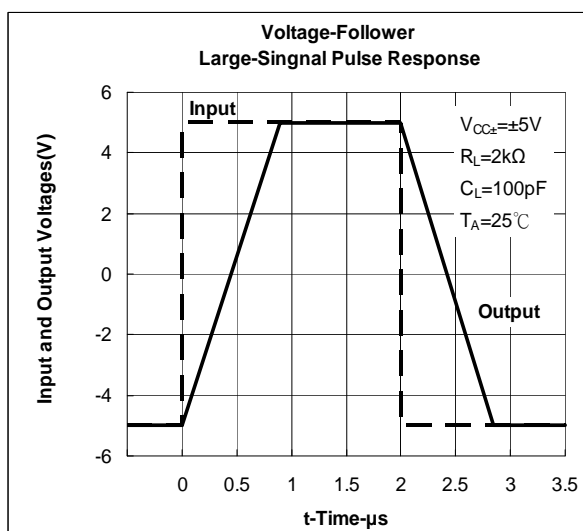
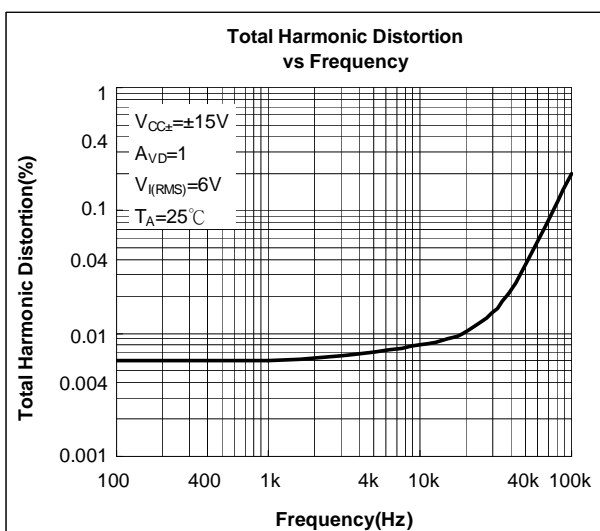
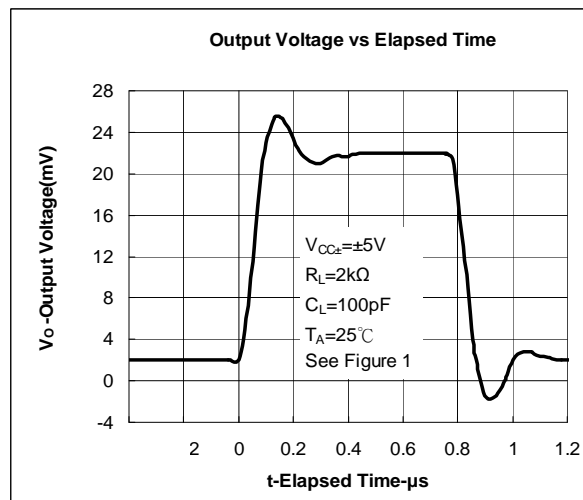
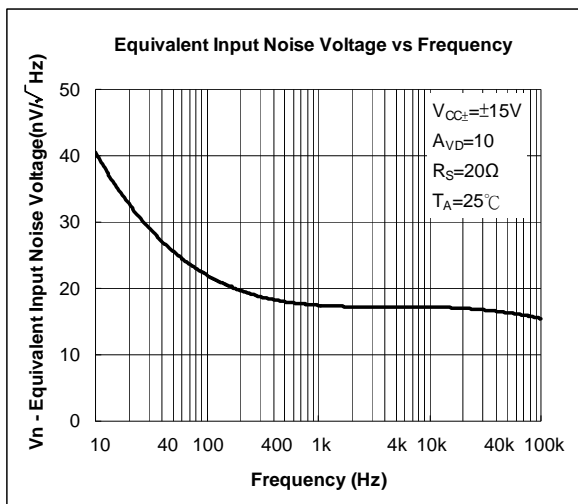
Typical Performance Characteristics (Continued)



Typical Performance Characteristics (Continued)



Typical Performance Characteristics (Continued)



Test Circuit

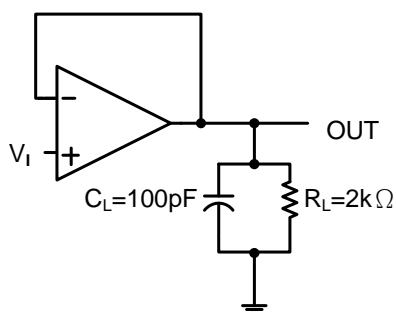


Figure 1. Unity-Gain Amplifier

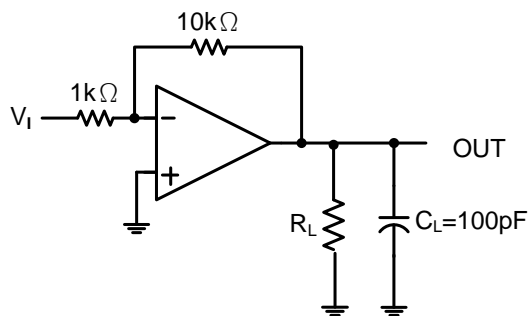
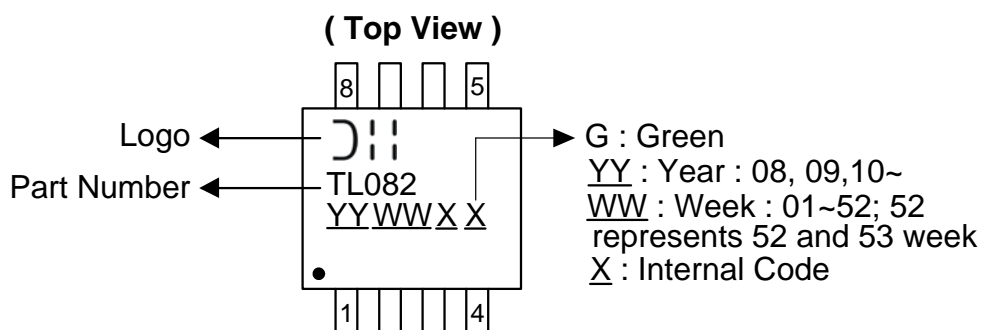


Figure 2. Gain-of-10 Inverting Amplifier

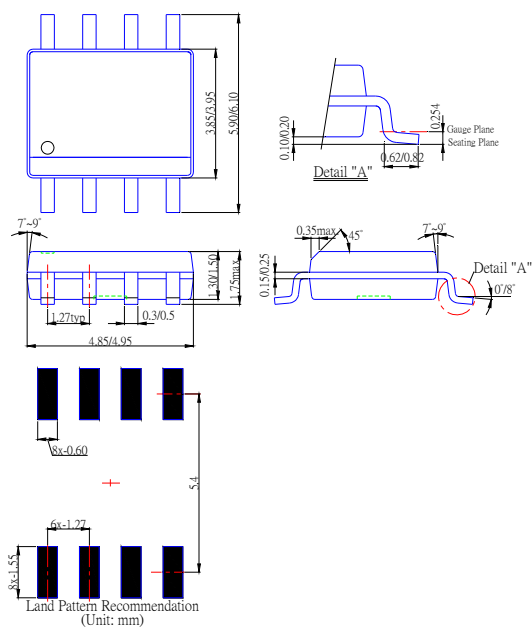
Marking Information

(1) SOP-8L



Package Information (All Dimensions in mm)

(1) Package type: SOP-8L



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